

## Features

- $V_{DS} = -40V$   $I_D = -50 A$
- $R_{DS(ON)} < -13m\Omega$  @  $V_{GS} = -10V$  (Type: 9.0m $\Omega$ )

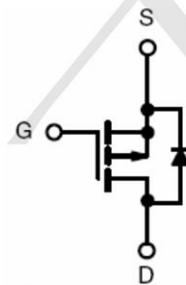
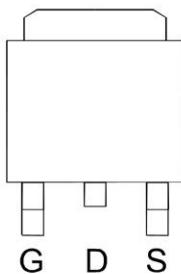
## Application

- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

## Package and Pin Configuration

(TO-252-3L)

Top View



## Marking:



## Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

| Symbol                | Parameter  | Rating     | Units |
|-----------------------|--|------------|-------|
| $V_{DS}$              | Drain-Source Voltage                             | -40        | V     |
| $V_{GS}$              | Gate-Source Voltage                              | $\pm 20$   | V     |
| $I_D@T_c=25^\circ C$  | Continuous Drain Current, $V_{GS} @ -10V^1$      | -50        | A     |
| $I_D@T_c=100^\circ C$ | Continuous Drain Current, $V_{GS} @ -10V^1$      | -32        | A     |
| $I_{DM}$              | Pulsed Drain Current <sup>2</sup>                | -105       | A     |
| EAS                   | Single Pulse Avalanche Energy <sup>3</sup>       | 146        | mJ    |
| $I_{AS}$              | Avalanche Current                                | -54        | A     |
| $P_D@T_c=25^\circ C$  | Total Power Dissipation <sup>4</sup>             | 52.1       | W     |
| $P_D@T_A=25^\circ C$  | Total Power Dissipation <sup>4</sup>             | 2          | W     |
| $T_{STG}$             | Storage Temperature Range                        | -55 to 150 | °C    |
| $T_J$                 | Operating Junction Temperature Range             | -55 to 150 | °C    |
| $R_{\theta JA}$       | Thermal Resistance Junction-Ambient <sup>1</sup> | 62         | °C/W  |
| $R_{\theta JC}$       | Thermal Resistance Junction-Case <sup>1</sup>    | 2.4        | °C/W  |

**Electrical Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise noted)**

| Symbol                                     | Parameter  | Conditions   | Min. | Typ.   | Max.      | Unit                       |
|--|--|--|------|--------|-----------|----------------------------|
| $\text{BV}_{\text{DSS}}$                   | Drain-Source Breakdown Voltage                     | $V_{\text{GS}}=0\text{V}$ , $I_{\text{D}}=-250\mu\text{A}$   | -40  |        | ---       | V                          |
| $\Delta \text{BV}_{\text{DSS}}/\Delta T_J$ | $\text{BV}_{\text{DSS}}$ Temperature Coefficient   | Reference to $25^\circ\text{C}$ , $I_{\text{D}}=-1\text{mA}$   | ---  | -0.023 | ---       | $\text{V}/^\circ\text{C}$  |
| $R_{\text{DS}(\text{ON})}$                 | Static Drain-Source On-Resistance <sup>2</sup>     | $V_{\text{GS}}=-10\text{V}$ , $I_{\text{D}}=-30\text{A}$   | ---  | 9.0    | 13        | $\text{m}\Omega$           |
|  |  | $V_{\text{GS}}=-4.5\text{V}$ , $I_{\text{D}}=-20\text{A}$  | ---  | 14     | 20        |                            |
| $V_{\text{GS}(\text{th})}$                 | Gate Threshold Voltage                             | $V_{\text{GS}}=V_{\text{DS}}$ , $I_{\text{D}}=-250\mu\text{A}$   | -1.0 | -1.6   | -2.5      | V                          |
| $\Delta V_{\text{GS}(\text{th})}$          | $V_{\text{GS}(\text{th})}$ Temperature Coefficient |  | ---  | 4.74   | ---       | $\text{mV}/^\circ\text{C}$ |
| $I_{\text{DSS}}$                           | Drain-Source Leakage Current                       | $V_{\text{DS}}=-32\text{V}$ , $V_{\text{GS}}=0\text{V}$ , $T_J=25^\circ\text{C}$                       | ---  | ---    | 1         | $\text{uA}$                |
|  |  | $V_{\text{DS}}=-32\text{V}$ , $V_{\text{GS}}=0\text{V}$ , $T_J=55^\circ\text{C}$                       | ---  | ---    | 5         |                            |
| $I_{\text{GSS}}$                           | Gate-Source Leakage Current                        | $V_{\text{GS}}=\pm 20\text{V}$ , $V_{\text{DS}}=0\text{V}$   | ---  | ---    | $\pm 100$ | nA                         |
| $g_{\text{fs}}$                            | Forward Transconductance                           | $V_{\text{DS}}=-5\text{V}$ , $I_{\text{D}}=-18\text{A}$  | ---  | 24     | ---       | S                          |
| $R_g$                                      | Gate Resistance                                    | $V_{\text{DS}}=0\text{V}$ , $V_{\text{GS}}=0\text{V}$ , $f=1\text{MHz}$                                | ---  | 7      | 14        | $\Omega$                   |
| $Q_g$                                      | Total Gate Charge (-4.5V)                          | $V_{\text{DS}}=-20\text{V}$ , $V_{\text{GS}}=-4.5\text{V}$ , $I_{\text{D}}=12\text{A}$                 | ---  | 27.9   | ---       | nC                         |
| $Q_{\text{gs}}$                            | Gate-Source Charge                                 |  | ---  | 7.7    | ---       |                            |
| $Q_{\text{gd}}$                            | Gate-Drain Charge                                  |  | ---  | 7.5    | ---       |                            |
| $T_{\text{d}(\text{on})}$                  | Turn-On Delay Time                                 | $V_{\text{DD}}=-15\text{V}$ , $V_{\text{GS}}=-10\text{V}$ , $R_g=3.3\Omega$ , $I_{\text{D}}=1\text{A}$ | ---  | 40     | ---       | ns                         |
| $T_r$                                      | Rise Time  |  | ---  | 35.2   | ---       |                            |
| $T_{\text{d}(\text{off})}$                 | Turn-Off Delay Time                                |  | ---  | 100    | ---       |                            |
| $T_f$                                      | Fall Time  |  | ---  | 9.6    | ---       |                            |
| $C_{\text{iss}}$                           | Input Capacitance                                  | $V_{\text{DS}}=-15\text{V}$ , $V_{\text{GS}}=0\text{V}$ , $f=1\text{MHz}$                              | ---  | 3500   | ---       | pF                         |
| $C_{\text{oss}}$                           | Output Capacitance                                 |  | ---  | 323    | ---       |                            |
| $C_{\text{rss}}$                           | Reverse Transfer Capacitance                       |  | ---  | 222    | ---       |                            |
| $I_s$                                      | Continuous Source Current <sup>1,5</sup>           | $V_G=V_D=0\text{V}$ , Force Current  | ---  | ---    | -50       | A                          |
| $I_{\text{SM}}$                            | Pulsed Source Current <sup>2,5</sup>               |  | ---  | ---    | -100      | A                          |
| $V_{\text{SD}}$                            | Diode Forward Voltage <sup>2</sup>                 | $V_{\text{GS}}=0\text{V}$ , $I_{\text{S}}=-1\text{A}$ , $T_J=25^\circ\text{C}$                         | ---  | ---    | -1        | V                          |

## Typical Characteristics

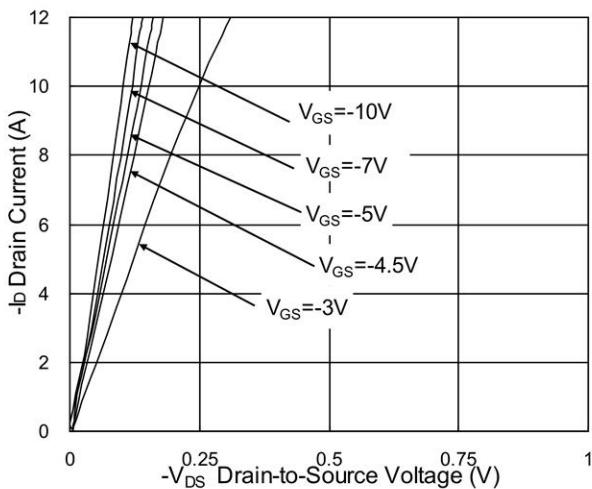


Fig.1 Typical Output Characteristics

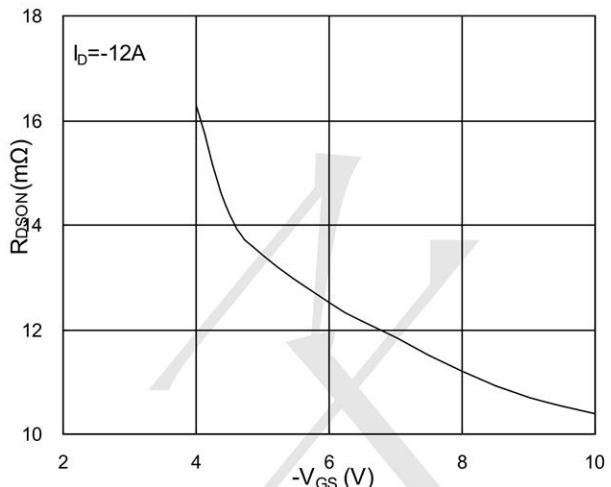


Fig.2 On-Resistance v.s Gate-Source

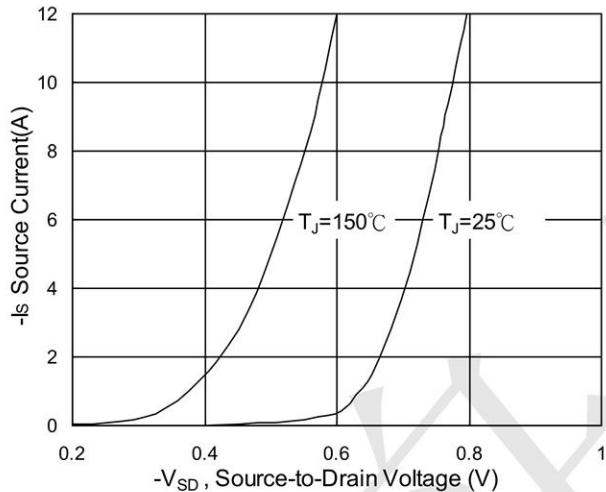


Fig.3 Forward Characteristics Of Reverse

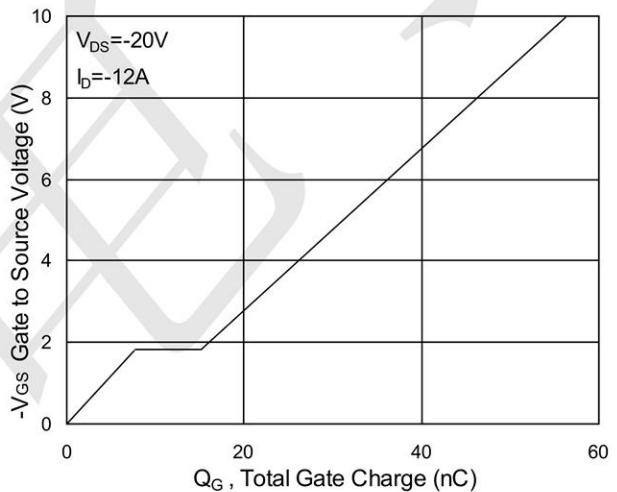


Fig.4 Gate-Charge Characteristics

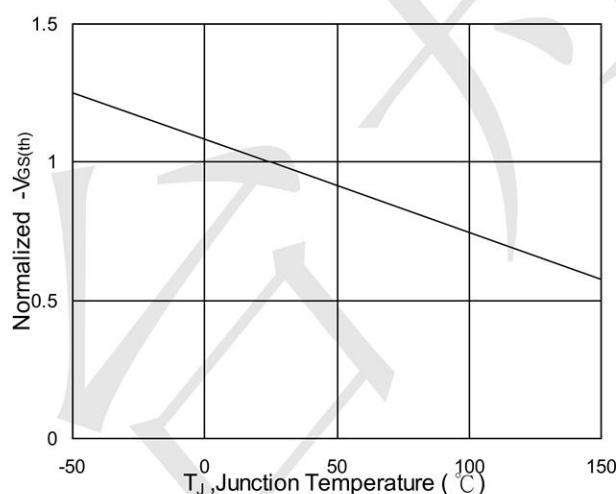


Fig.5 Normalized  $V_{GS(th)}$  v.s  $T_J$

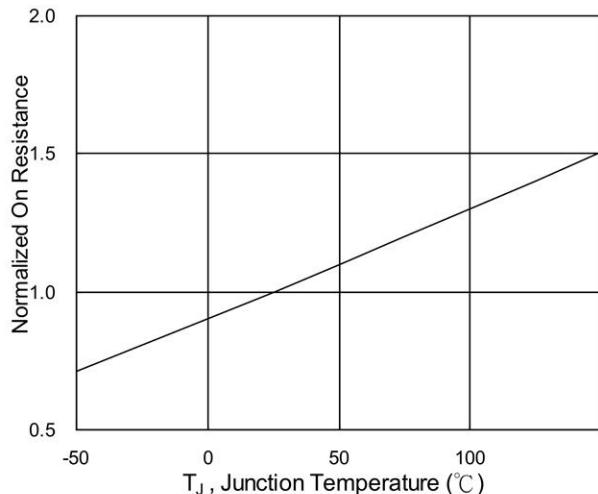
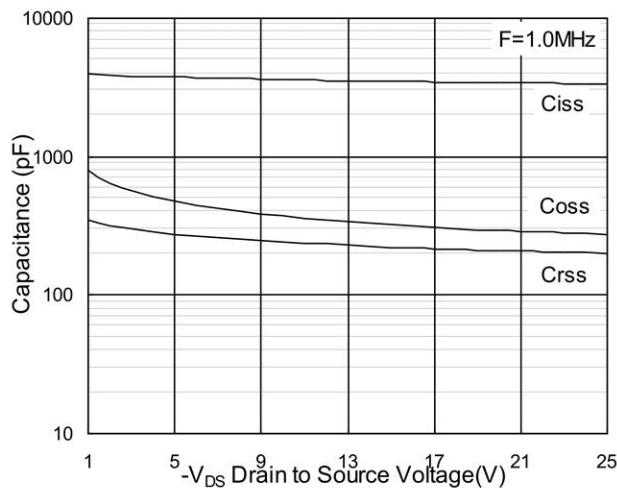
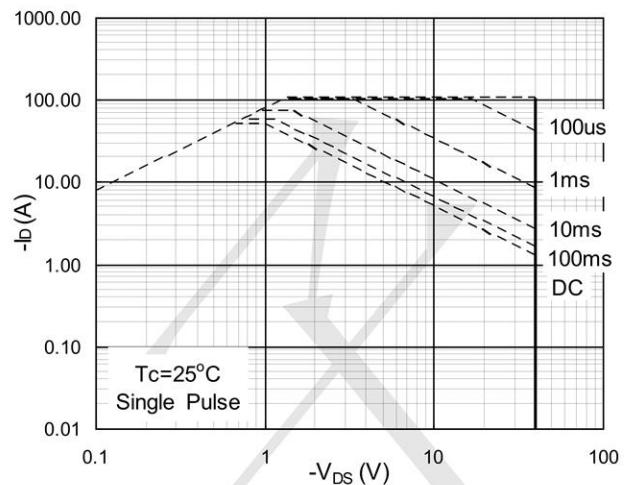


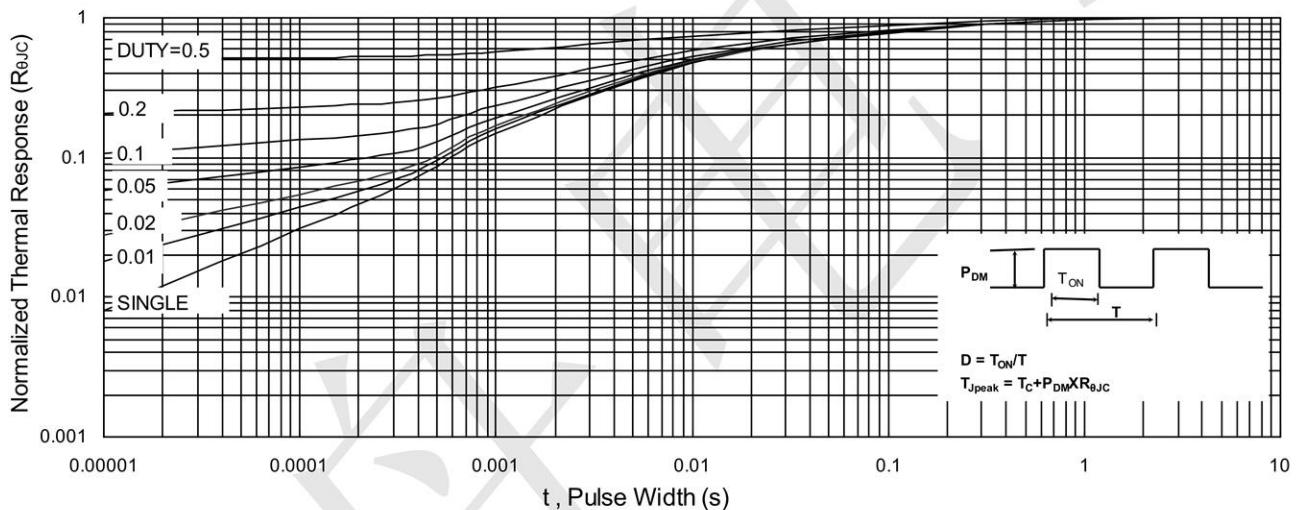
Fig.6 Normalized  $R_{DS(on)}$  v.s  $T_J$



**Fig.7 Capacitance**

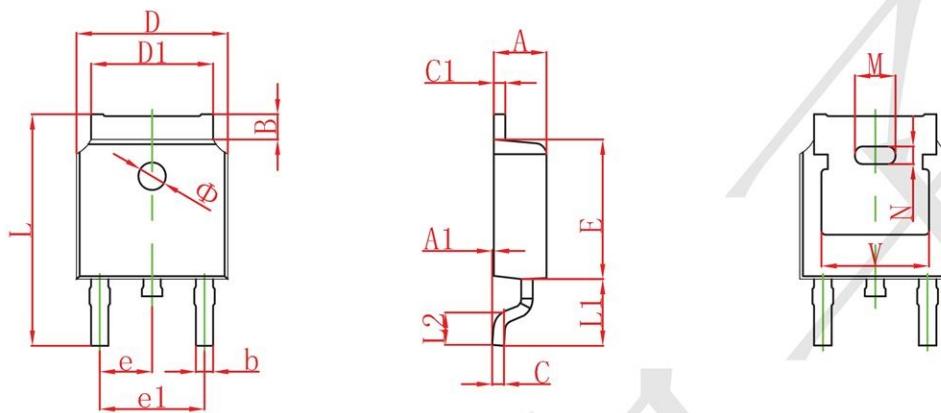


**Fig.8 Safe Operating Area**



**Fig.9 Normalized Maximum Transient Thermal Impedance**

### TO252 Package Information



| Symbol | Dimensions In Millimeters |        | Dimensions In Inches |       |
|--------|---------------------------|--------|----------------------|-------|
|        | Min.                      | Max.   | Min.                 | Max.  |
| A      | 2.200                     | 2.380  | 0.087                | 0.094 |
| A1     | 0.000                     | 0.100  | 0.000                | 0.004 |
| B      | 0.800                     | 1.400  | 0.031                | 0.055 |
| b      | 0.710                     | 0.810  | 0.028                | 0.032 |
| c      | 0.460                     | 0.560  | 0.018                | 0.022 |
| c1     | 0.460                     | 0.560  | 0.018                | 0.022 |
| D      | 6.500                     | 6.700  | 0.256                | 0.264 |
| D1     | 5.130                     | 5.460  | 0.202                | 0.215 |
| E      | 6.000                     | 6.200  | 0.236                | 0.244 |
| e      | 2.286 TYP.                |        | 0.090 TYP.           |       |
| e1     | 4.327                     | 4.727  | 0.170                | 0.186 |
| M      | 1.778REF.                 |        | 0.070REF.            |       |
| N      | 0.762REF.                 |        | 0.018REF.            |       |
| L      | 9.800                     | 10.400 | 0.386                | 0.409 |
| L1     | 2.9REF.                   |        | 0.114REF.            |       |
| L2     | 1.400                     | 1.700  | 0.055                | 0.067 |
| V      | 4.830 REF.                |        | 0.190 REF.           |       |
| Ø      | 1.100                     | 1.300  | 0.043                | 0.051 |